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	Docket No.:	57017.P025						Pate
		MATTHEWS.	 J.					<u> </u>
Seral No.:	07/8			(invento	or(s))			· ·
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57017.P025



<u>Patent</u>

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

MATTHEWS, J.

Serial No. 07/863,791

Filing Date: April 6, 1992

For: METHOD FOR IMPROVED LITHOGRAPHIC PATTERNING IN A SEMICONDUCTOR FABRICATION PROCESS Examiner:

Dodson, S.

Art Unit:

1503

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APR 2 2 1995

GROUP 150

Amendment

Box Non-Fee Amendments (Pats) Commissioner of Patents and Trademarks Washington, D.C. 20231

Sir:

In response to the Office Action dated March 29, 1993, please enter the following amendment and consider the following remarks:

IN THE SPECIFICATION:

On page 4, line 9, change "rediation" to -- radiation --.
On page 7, line 32, delete "."

IN THE CLAIMS:

Please cancel claim 13 without prejudice.

Sul,

- 1. (Amended) A method of printing a two-dimensional feature on a substrate, said feature having first and second edges spaced in close proximity to one another, said method comprising the steps of:
 - (a) depositing a radiation-sensitive material on said substrate;
- (b) providing a first mask image segment which corresponds to said first edge;
- (c) exposing said first mask image segment with radiation using an imaging tool to produce a first pattern edge gradient, said first pattern edge gradient defining said first edge of said two-dimensional feature in said material;